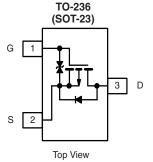




P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	V _{GS(th)} (V)	I _D (mA)		
- 60	6 at V _{GS} = - 10 V	- 1 to - 3	- 185		



Marking Code: 6Kwll

6K = Part Number Code for TP0610K w = Week Code

II = Lot Traceability

Ordering Information: TP0610K-T1-E3 (Lead (Pb)-free)

TP0610K-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- High-Side Switching
- Low On-Resistance: 6 Ω
- Low Threshold: 2 V (typ.)
- Fast Swtiching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- 2000 V ESD Protection
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- · Battery Operated Systems
- Power Supply Converter Circuits
- · Solid-State Relays

BENEFITS

- · Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- · Easily Driven without Buffer

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V_{DS}	- 60	٧	
Gate-Source Voltage		V _{GS}	± 20	V	
Outline Paris Outline	T _A = 25 °C	I _D	- 185	mA	
Continuous Drain Current ^a	T _A = 100 °C		- 115		
Pulsed Drain Current ^b	·	I _{DM}	- 800		
Develop Planta attack	T _A = 25 °C	P _D	350	mW	
Power Dissipation ^a	T _A = 100 °C		140		
Maximum Junction-to-Ambient ^a	·	R _{thJA}	350	°C/W	
Operating Junction and Storage Temperature Range		T _{J,} T _{stg}	- 55 to 150	°C	

Notes

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

FREE

TP0610K

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SPECIFICATIONS T _A = 25	°C, unless oth	erwise noted					
			Limits				
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V, I}_{D} = -10 \mu\text{A}$ - 60				V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3] v	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 10	μΑ	
Cata Badul asluana		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 200		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			± 500	nA	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100		
Zava Cata Valtaga Drain Current		V _{DS} = - 60 V, V _{GS} = 0 V	_{OS} = - 60 V, V _{GS} = 0 V		- 25		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 85 °C			- 250		
On-State Drain Current ^a	,	V _{GS} = - 10 V, V _{DS} = - 4.5 V	- 50				
	I _{D(on)}	V _{GS} = - 10 V, V _{DS} = - 10 V	- 600			mA	
		V _{GS} = - 4.5 V, I _D = - 25 mA	10		10		
Drain-Source On-Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 500 mA			6	Ω	
		V _{GS} = - 10 V, I _D = - 500 mA, T _J =125 °C			9		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 100 mA	80			mS	
Diode Forward Voltage	V _{SD}	I _S = - 200 mA, V _{GS} = 0 V			- 1.4	V	
Dynamic	<u>.</u>						
Total Gate Charge	Qg			1.7		nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = -30 \text{ V}, V_{GS} = -15 \text{ V}$ $I_{D} \cong -500 \text{ mA}$		0.26			
Gate-Drain Charge	Q _{gd}	1D = 000 m/r		0.46			
Input Capacitance	C _{iss}			23		pF	
Output Capacitance	C _{oss}	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz		10			
Reverse Transfer Capacitance	C _{rss}	1 - 1 1411.12		5			
Switching ^b							
Turn-On Time	t _{d(on)}	$V_{DD} = -25 \text{ V}, R_{L} = 150 \Omega$		20		ns	
Turn-Off Time	t _{d(off)}	$I_D \cong$ - 200 mA, $V_{GEN} =$ - 10 V, $R_g =$ 10 Ω		35			

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.

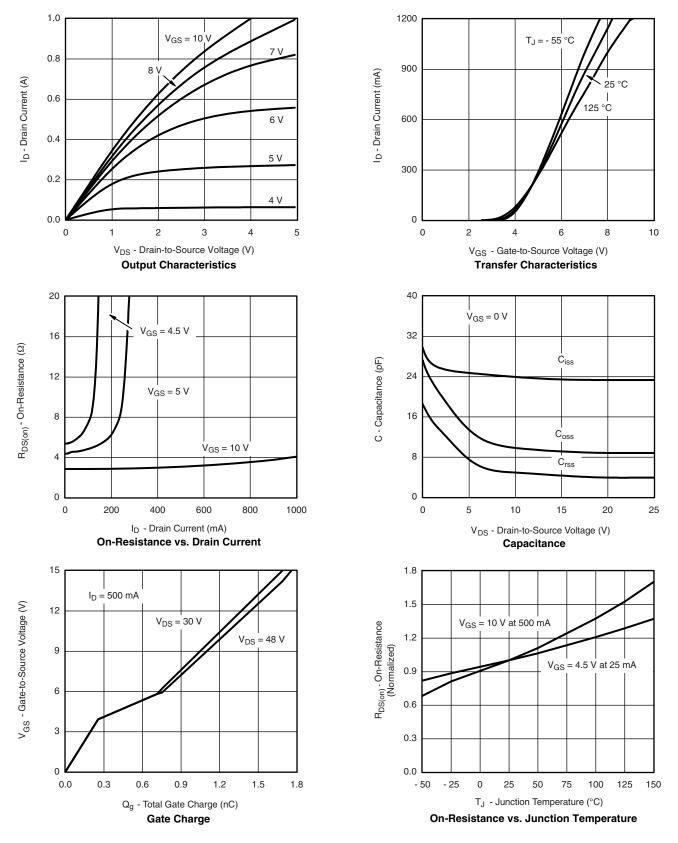
b. Switching time is essentially independent of operating temperature.







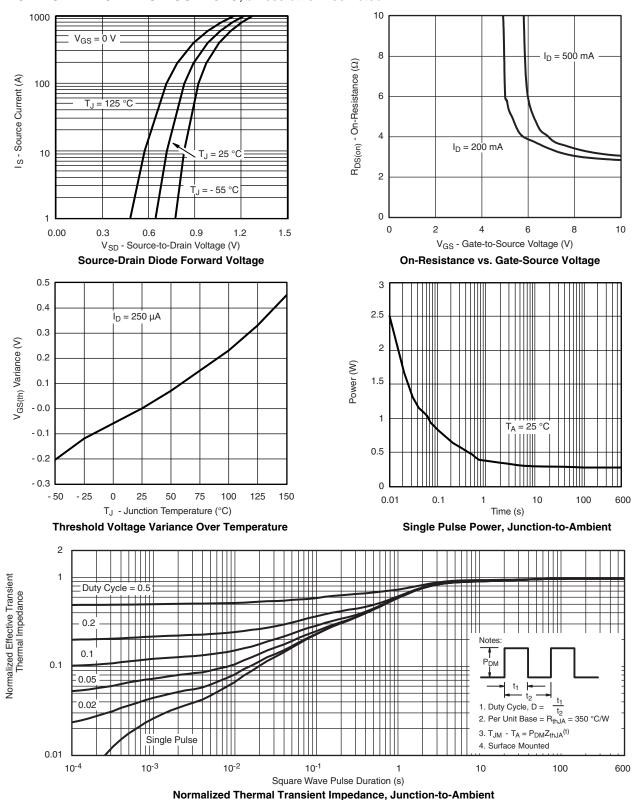
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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SOT-23 (TO-236): 3-LEAD







Dim	MILLIMETERS		INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.9	0.95 BSC 0.0374 Ref		4 Ref	
e ₁	1.9) BSC 0.074		8 Ref	
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.5	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°	
FCN: S-03946-Rev K 09-	lul-01	•			

ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

Document Number: 71196 www.vishay.com 09-Jul-01



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index

APPLICATION NOTE



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